Dual 2-to-4 line Decoder / Demultiplexers

HITACHI

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Description

The HD74LV139A is designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. The active-low enable input can be used as a data line in demultiplexing applications.

This decoder/demultiplexer features fully buffered inputs, each of which represents only one normalized load to its driving circuit.

Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0 \text{ V}$ to 5.5 V operation
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- All outputs V_0 (Max.) = 5.5 V (@ V_{CC} = 0 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.3 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Output current ± 6 mA (@V_{CC} = 3.0 V to 3.6 V), ± 12 mA (@V_{CC} = 4.5 V to 5.5 V)

Function Table

Inputs

	Select		Outputs			
G ₁	В	Α	Y0	Y1	Y2	Y3
Н	Х	X	Н	Н	Н	Н
L	L	L	L	Н	Н	Н
L	L	Н	Н	L	Н	Н
L	Н	L	Н	Н	L	Н
L	Н	Н	Н	Н	Н	L

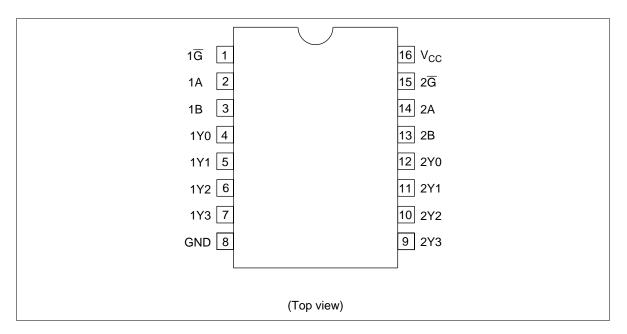
Note: H: High level

L: Low level

X: Immaterial



Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{cc}	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	-0.5 to $V_{cc} + 0.5$	V	Output: H or L
		-0.5 to 7.0	=	V _{cc} : OFF
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	I _{ok}	±50	mA	$V_o < 0 \text{ or } V_o > V_{cc}$
Continuous output current	Io	±25	mA	$V_{o} = 0$ to V_{cc}
Continuous current through V _{cc} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air)*3	P _T	785	mW	SOP
		500	-	TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

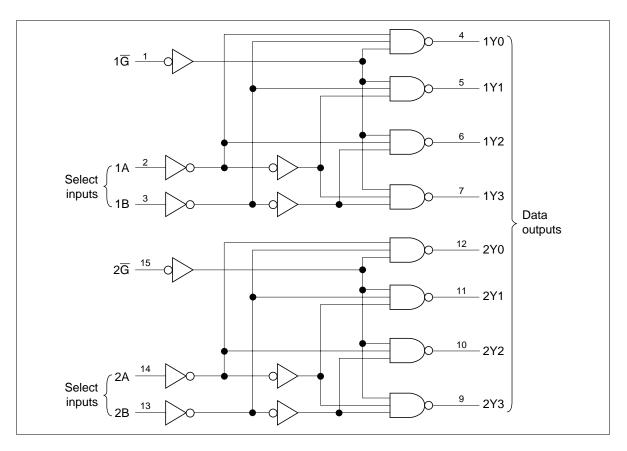
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{cc}	2.0	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	V _{cc}	V	H or L
Output current	I _{OH}	_	-50	μΑ	V _{CC} = 2.0 V
		_	-2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	-6		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
	I _{OL}	_	50	μΑ	V _{CC} = 2.0 V
		_	2	mA	$V_{cc} = 2.3 \text{ to } 2.7 \text{ V}$
		_	6		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt/Δν	0	200	ns/V	$V_{cc} = 2.3 \text{ to } 2.7 \text{ V}$
		0	100		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

• $Ta = -40 \text{ to } 85^{\circ}C$

Item	Symbol	V _{cc} (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	_	_		
		3.0 to 3.6	$V_{CC} \times 0.7$	_	_	_	
		4.5 to 5.5	$V_{CC} \times 0.7$	_	_	_	
	V _{IL}	2.0	_	_	0.5	_	
		2.3 to 2.7	_	_	$V_{\text{CC}}\!\times\!0.3$		
		3.0 to 3.6	_	_	$V_{CC} \times 0.3$	_	
		4.5 to 5.5	_	_	$V_{CC} \times 0.3$		
Output voltage	V_{OH}	Min to Max	$V_{CC} - 0.1$	_	_	V	$I_{OH} = -50 \mu A$
		2.3	2.0	_	_	_	$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_		$I_{OH} = -6 \text{ mA}$
		4.5	3.8	_	_	_	$I_{OH} = -12 \text{ mA}$
	V_{OL}	Min to Max	_	_	0.1		$I_{OL} = 50 \mu A$
		2.3	_	_	0.4		I _{OL} = 2 mA
		3.0	_	_	0.44	_	I _{OL} = 6 mA
		4.5	_	_	0.55	_	I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_1 = 5.5 \text{ V or GND}$
Quiescent supply current	I _{cc}	5.5	_	_	20	μА	$V_I = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I _{OFF}	0	_	_	5	μΑ	V_1 or $V_0 = 0 V$ to 5.5 V
Input capacitance	C _{IN}	3.3	_	1.9	_	pF	$V_{I} = V_{CC}$ or GND
	1.4.			41			

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

• $V_{CC} = 2.5 \pm 0.2 \text{ V}$

		Ta = 25°C		Ta = -	$Ta = -40 \text{ to } 85^{\circ}\text{C}$					
Item Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)	
Propa- gation delay time	t _{PLH} /t _{PHL}	_	7.7	17.6	1.0	21.0	ns	C _L = 15 pF	A or B	Y
		_	10.2	22.5	1.0	26.5	=	C _L = 50 pF		
		_	7.4	15.8	1.0	19.0	_	C _L = 15 pF	G	-
		_	9.9	20.2	1.0	24.0	_	C ₁ = 50 pF		

• $V_{CC} = 3.3 \pm 0.3 \text{ V}$

		Ta =	25°C		Ta = -	40 to 85°C				
Item	Symbol	ymbol Min Typ Max Min Max	Unit	Test Conditions	FROM (Input)	TO (Output)				
Propa- gation delay time	t _{PLH} /t _{PHL}	_	5.3	11.0	1.0	13.0	ns	C _L = 15 pF	A or B	Υ
		_	7.3	14.5	1.0	16.5	_	C _L = 50 pF		
		_	5.1	9.2	1.0	11.0	-	C _L = 15 pF	G	
		_	7.0	12.7	1.0	14.5	-	C _L = 50 pF		

• $V_{CC} = 5.0 \pm 0.5 \text{ V}$

		Ta =	25°C		Ta = −40 to 85°C					
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propa- gation delay time	t _{PLH} /t _{PHL}	_	3.7	7.2	1.0	8.5	ns	C _L = 15 pF	A or B	Y
		_	5.2	9.2	1.0	10.5	=	C _L = 50 pF		
		_	3.5	6.3	1.0	7.5	_	C _L = 15 pF	G	
		_	4.9	8.3	1.0	9.5	_	C _L = 50 pF		

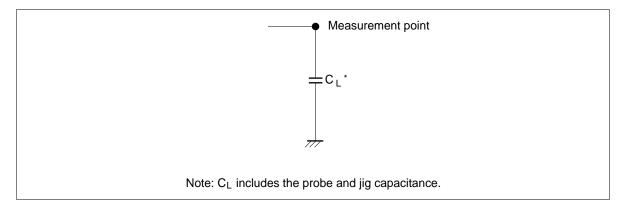
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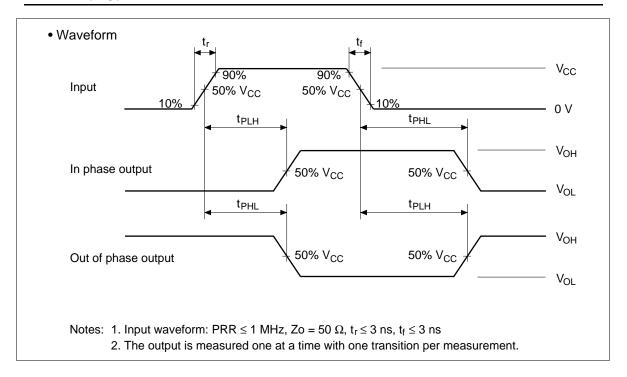
Operating Characteristics

• $C_L = 50 pF$

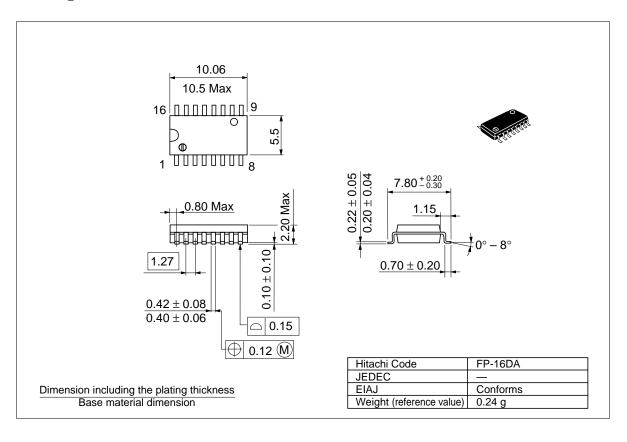
			1a = 25	°C			
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	C_{PD}	3.3	_	17.3	_	pF	f = 10 MHz
		5.0	_	18.2	_		

Test Circuit

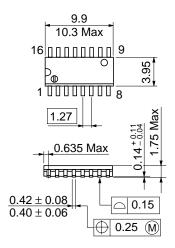




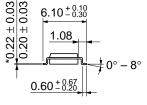
Package Dimensions







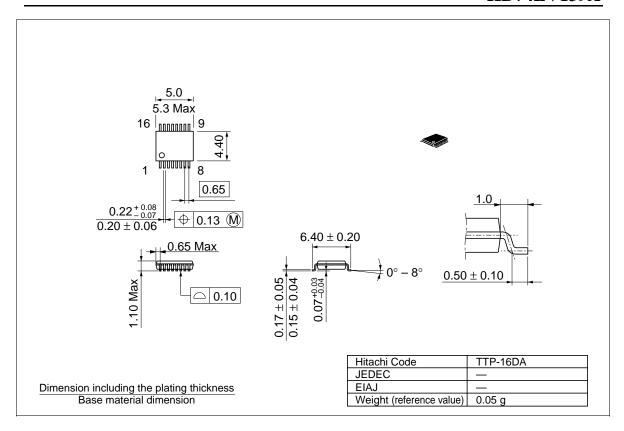




Dimension including the plating thickness

Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g



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Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park

Maidenhead Berkshire SL6 8YA, United Kingdom

Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Lower Cookham Road

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666

Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218

Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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